TOSHIBA Bi-CD Integrated Circuit Silicon Monolithic

TB6633AFNG

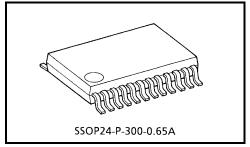
3-Phase Full-Wave PWM Driver for Sensorless DC Motors

The TB6633AFNG is a three-phase full-wave PWM driver for sensorless brushless DC (BLDC) motors. It controls motor rotation speed by changing the PWM duty cycle, based on the voltage of an analog control input.

Features

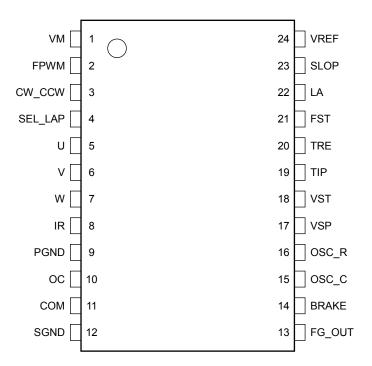
- Sensorless drive in three-phase full-wave mode
- PWM chopper control
- Controls the PWM duty cycle based on an analog input (7-bit ADC)
- Output current: IOUT = 0.6 A typ. (1 A max)
- Power supply: VM = 4.5 V to 22 V (25 V max)
- · Forward and reverse rotation
- Lead angle control (0°, 15° and 30°)
- Overlapping commutation (120°, 135° and 150°)
- Selectable duty cycle modulation period upon state transitions of phase signals
- Rotation speed detecting signal (FG_OUT)
 - TB6633FNG:3 pulses per electrical degree
 - TB6633AFNG:1 pulses per electrical degree
- Adjustable startup settings
- Forced commutation frequency control (fosc / (6 \times 217), fosc / (6 \times 218) and fosc / (6 \times 219))
- Selectable PWM frequency
- Restart feature
- Overcurrent protection (ISD)
- Thermal shutdown (TSD)
- Undervoltage lockout (LVD)
- Current limiter
- Short brake control

Note: 8 pin (IR) of this product is sensitive to electrostatic discharge. When handling this product, protect the environment to avoid electrostatic discharge.



Weight: 0.136 g (typ.)

Pin Assignment





Pin Description

| 1 VM 2 FPW | | _ | Motor power supply pin |
|---------------|-----|---|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 2 FPW | М | | meter perior cappi, pin |
| | | 1 | PWM frequency (f _{PWM}) select input (This pin has a pull-down resistor.) High : f _{PWM} \simeq f _{OSC} / 128 |
| 3 CW_C | CW | ı | Rotation direction select input (This pin has a pull-down resistor.) High: Counterclockwise ($U \rightarrow W \rightarrow V$) Low, Open: Clockwise ($U \rightarrow V \rightarrow W$) |
| 4 SEL_L | .AP | ı | Overlapping commutation select pin (This pin has a pull-down resistor.) High : Overlapping commutation Low, Open : 120° commutation |
| 5 U | | 0 | U-phase output |
| 6 V | | 0 | V-phase output |
| 7 W | | 0 | W-phase output |
| 8 IR | | _ | Connection pin for an output shunt resistor |
| 9 PGN | ID | _ | Power ground pin |
| 10 OC | ; | ı | Overcurrent detection input (This pin has a pull-down resistor.) All PWM output signals are stopped when OC ≥ 0.25 V (typ.). |
| 11 CON | И | I | Connection pin for the center tap of the motor |
| 12 SGN | ID | _ | Signal ground pin |
| 13 FG_O | UT | 0 | Rotation speed output pin (open-drain) This output is held low at startup and when an abnormality is detected. In sensorless mode, pulses are generated at 1ppr according to the back-EMF. Note: 1ppr = 1 pulses per electrical degree (With a four-pole motor, two pulses are generated per revolution.) |
| 14 BRAK | KE | I | Short brake control pin (This pin has a pull-down resistor.) High : Short brake Low, Open : Normal operation |
| 15 OSC_ | _C | _ | OSC_C: Connection pin for the oscillator capacitor |
| 16 OSC_ | _R | _ | OSC_R: Connection pin for the oscillator resistor Example: Internal oscillating frequency (f_{OSC}) $\simeq 5.1$ MHz (typ.) when OSC_C = 68 pF and OSC_R = 20 k Ω . |
| 17 VSF | Þ | Ι | Motor speed control input (This pin has a pull-down resistor.) $0 \leq VSP \leq V_{AD} \text{ (L)}; 1 \text{ V (typ.)} \qquad : \text{Output OFF} \\ V_{AD} \text{ (L)} \leq VSP \leq V_{AD} \text{ (H)}; 4 \text{ V (typ.)} \qquad : \text{Sets the PWM duty cycle based on the analog input.} \\ V_{AD} \text{ (H)} \leq VSP \leq VREF \qquad : 100 \% \text{ duty cycle (127 / 128)}$ |
| 18 VST | г | _ | Duty cycle setting pin for DC excitation and forced commutation modes $0 \le VST \le V_{AD}$ (L); 1 V (typ.) : 0 % duty cycle V_{AD} (L) $\le VST \le V_{AD}$ (H); 4 V (typ.) : Sets the PWM duty cycle based on the analog input. V_{AD} (H) $\le VST \le VREF$: 100 % duty cycle (127 / 128) |
| 19 TIP |) | _ | Connection pin for a capacitor to set the DC excitation time |
| 20 TRE | | _ | Connection pin for a capacitor to set the restart time upon abnormality detection |
| 21 FST | Г | _ | Forced commutation frequency select input (This pin has a pull-down resistor.) Forced commutation frequency (fgT): cycles per second equivalent to an electrical degree FST = High = fsT \simeq fosc / (6 \times 2 ¹⁷) Example) fsT \simeq 6.4 Hz @ fosc = 5.1 MHz FST = Middle = fsT \simeq fosc / (6 \times 2 ¹⁸) Example) fsT \simeq 3.2 Hz @ fosc = 5.1 MHz FST = Low, Open = fsT \simeq fosc / (6 \times 2 ¹⁹) Example) fsT \simeq 1.6 Hz @ fosc = 5.1 MHz |
| 22 LA | | I | Lead angle select input (This pin has a pull-down resistor.) LA = High $\simeq 30^\circ$ lead angle LA = Middle $\simeq 15^\circ$ lead angle LA = Low, Open $\simeq 0^\circ$ lead angle |
| 23 SLOI | Р | I | Modulation scheme select input for phase signal state transitions (This pin has a pull-down resistor.) SLOP = High \simeq modulation SLOP = Middle \simeq test mode SLOP = Low, Open \simeq No modulation |
| 24 VRE | F | _ | Reference voltage output; VREF = 5 V (typ.) |

Functional Description

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

Timing charts may be simplified for explanatory purposes.

1. Sensorless Drive Mode

Based on the analog voltage input at the VSP pin for a startup operation, the rotor is aligned to a known position in DC excitation mode. Then, the forced commutation signal is generated to start the motor rotation. As the motor rotates, the back-EMF occurs in each phase of the coil. When an input signal indicating the polarity of three phase voltage of the motor, including the back-EMF, is detected as a position signal, the motor driving signal is automatically switched from forced commutation signal to the normal commutation PWM signal that is based on the position signal input (back-EMF). Then, a BLDC motor starts running in sensorless commutation mode.

2. Startup Operation

At startup, no induced voltage is generated due to the stationary motor, and the rotor position cannot be detected in sensorless mode. Therefore, the TB6633AFNG rotor is first aligned to a known position in DC excitation mode for an appropriate period of time, and then the motor is started in forced commutation mode.

The DC excitation time is determined via the TIP pin. The forced commutation frequency is determined via the FST pin. The duty cycles for DC excitation and forced commutation modes are determined by the VST voltage. For sensorless mode, the PWM duty cycle is determined by the VSP value. A speed-control voltage should be applied to the VSP pin to start and stop the motor operation, and to control the motor speed. Since the time settings and startup torques (output duty cycle) for DC excitation and forced commutation vary depending on the motor type and load, they should be adjusted experimentally.

1) DC Excitation Mode

The DC excitation time is determined via the TIP pin.

DC excitation time: $T_2 = C_2 \times TIP$ pin voltage / TIP pin charge current

 $C_2 = 0.1 \mu F$, $T_2 = 0.1 \mu F \times 3 V (typ.) / 3 \mu A (typ.) = 0.1 s$

2) Forced Commutation Mode

The forced commutation frequency is determined via the FST pin.

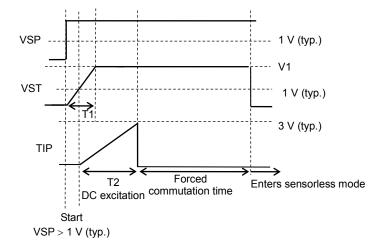
(The FST pin has a pull-down resistor.)

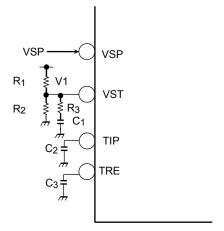
FST = High = Forced commutation frequency $f_{ST} \simeq f_{osc} / (6 \times 2^{17})$

FST = Middle = Forced commutation frequency fST \simeq f_{osc} / (6 × 2¹⁸)

FST = Low, Open = Forced commutation frequency fsT \simeq fosc / (6 \times 219)

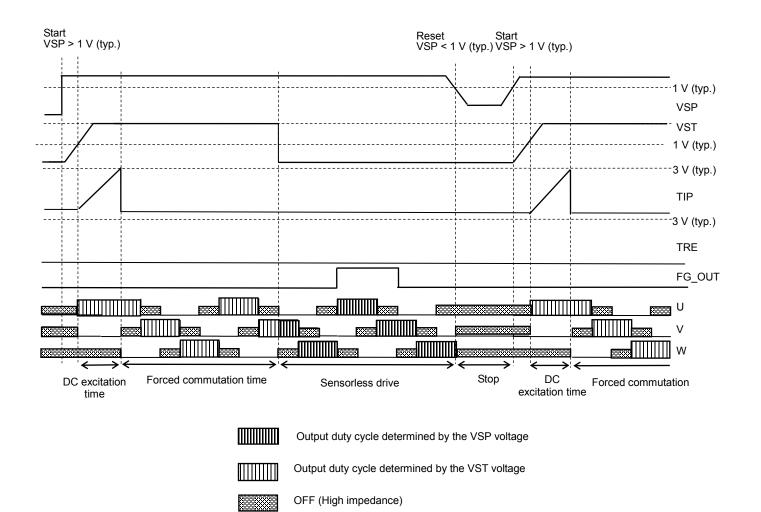
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3) Timing Diagram of the Startup Operation (CW_CCW = Low: Clockwise rotation)



3. Restart Operation

When any abnormality is detected, output signals are turned off (high impedance) during the operation restart time.

The following events are detected as abnormalities:

- 1. The forced commutation time exceeds eight electrical-degree period.
- 2. The ISD circuit is activated.
- 3. The TSD circuit is activated.
- 4. The rotation speed falls below the forced commutation frequency for sensorless mode.
- 5. The short brake mode is exited.
- 6. The input is switched at CW_CCW pin for sensorless mode.
- 7. Maximum commutation frequency (FMAX)

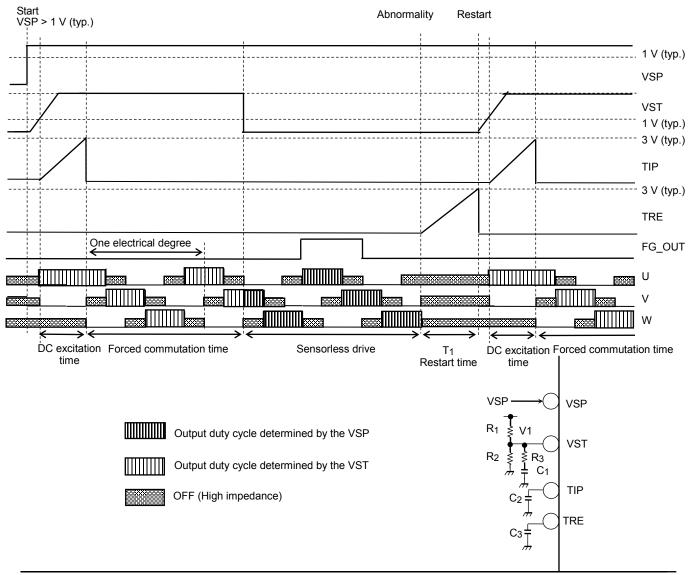
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 \begin{array}{ll} FST = High = FMAX = f_{osc} / \left(6 \times 2^{11}\right) & Example \right) FMAX = 400 Hz \ per \ electrical \ degree \ @ \ f_{osc} = 5.1 \ MHz \\ FST = Middle = FMAX = f_{osc} / \left(6 \times 2^{11}\right) & Example \right) FMAX = 400 Hz \ per \ electrical \ degree \ @ \ f_{osc} = 5.1 \ MHz \\ FST = Low = FMAX = f_{osc} / \left(6 \times 2^{12}\right) & Example \right) FMAX = 200 Hz \ per \ electrical \ degree \ @ \ f_{osc} = 5.1 \ MHz \\ Example = FMAX = f_{osc} / \left(6 \times 2^{12}\right) & Example = f_{osc}
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The restart time is determined via the TRE pin as follows:

Restart time: $T_1 = C_3 \times TRE$ pin voltage / TRE pin charge current $C_3 = 1 \mu F$, $T_1 = 1 \mu F \times 3 V$ (typ.) / $3 \mu A$ (typ.) = 1 s (typ.)

For example, when the motor does not rotate due to motor locking or when a mode transition from forced commutation mode to sensorless mode does not properly occur, the TB6633AFNG begins cycling into the following operation:

Operation start when VSP >1 V (typ.) \rightarrow DC excitation time \rightarrow Forced commutation time of eight electrical-degree period \rightarrow Restart time \rightarrow DC excitation time...



TB6633AFNG

Absolute Maximum Ratings (Note) (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit |
|-----------------------|----------------------------|-------------------|------|
| Power supply voltage | VM | 25 | V |
| Input voltage | V _{IN1} (Note 1) | -0.3 to 6.0 | V |
| Input voltage | V _{IN2} (Note 2) | -0.3 to 25 | V |
| Output valtage | V _{OUT1} (Note 3) | 25 -0.3 to 6.0 | V |
| Output voltage | Vour2 (Note 4) | 6.0 | V |
| | IOUT1 (Note 5) | 1 (Note 8) | Α |
| Output current | IOUT2 (Note 6) | 5 | mA |
| | I _{OUT3} (Note 7) | 5 | mA |
| Power dissipation | PD | 0.78 (Note 9) | W |
| Operating temperature | Topr | -40 to 85 | °C |
| Storage temperature | T _{stg} | -55 to 150 | °C |

Note: The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings.

Exceeding the rating (s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.

Please use the TB6633AFNG within the specified operating ranges.

Note 1: V_{IN1} is applicable to the voltage at the following pins: FPWM, VSP, CW_CCW, LA, OC, SEL_LAP, FST, BRAKE and SLOP

Note 2: V_{IN2} is applicable to the voltage at the COM pin.

Note 3: Vout1 is applicable to the voltage at the following pins: U, V and W

Note 4: VOUT2 is applicable to the voltage at the FG_OUT pin.

Note 5: IOUT1 is applicable to the current at the following pins: U, V and W

Note 6: IOUT2 is applicable to the current at the FG_OUT pin.

Note 7: IOUT3 is applicable to the current at the VREF pin.

Note 8: Output current may be limited by the ambient temperature or the device implementation. The maximum junction temperature should not exceed T_{imax} = 150°C

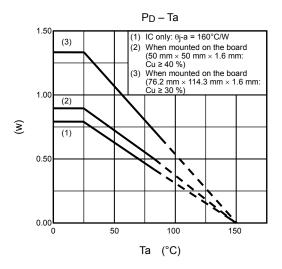
Note 9: Measured for the IC only. (Ta = 25°C)

Operating Ranges

| Characteristics | Symbol | Min | Тур. | Max | Unit |
|----------------------------------|--------------------|-----|------|-----|------|
| Power supply voltage 1 | VM _{opr1} | 5.5 | 12 | 22 | ٧ |
| Power supply voltage 2 (Note 10) | VM _{opr2} | 4.5 | 5 | 5.5 | V |

Note 10: Please pay attention to use the IC when VM is 5.5 V or less because the characteristics of the output ON resistance and the output voltage of VREF change.

Package Power Dissipation



Electrical Characteristics (Ta = 25°C, VM = 12 V, unless otherwise specified)

| Characteristics | Symbol | Test Conditions | Min | Тур. | Max | Unit |
|-------------------------------------------|----------------------|----------------------------------------------------------------------------------------------------------------------------------------------|-----|--------------------------------|-----|------|
| Static power supply current of VM | IM | $\begin{aligned} & \text{VSP = VST = 0 V,} \\ & \text{IR = TIP = COM = GND,} \\ & \text{The OSC_C = 68 pF, OSC_R = 20 k} \\ \end{aligned}$ | _ | 3.5 | 6 | mA |
| Dynamic power supply current of VM | IM (opr) | $VSP = VST = 2.5 \text{ V}, \\ IR = TIP = COM = GND, \\ The OSC_C = 68 \text{ pF, OSC_R} = 20 \text{ k}\Omega$ | _ | 4 | 7 | mA |
| | I _{IN1} (H) | V _{IN} = 5 V FPWM, CW_CCW, SEL_LAP, BRAKE, FST, SLOP, LA | _ | 50 | 75 | |
| Input current | I _{IN1} (L) | V _{IN} = 0 V, FPWM, CW_CCW, SEL_LAP, BRAKE, FST, SLOP, LA | -1 | 0 | _ | μА |
| | I _{IN2} (H) | V _{IN} = 5 V, VSP | _ | 50 | 75 | |
| | I _{IN2} (L) | V _{IN} = 0 V, VSP | -1 | 50 75 0 — 5.5 0 — 0.8 | | |
| | V _{IN1} (H) | | 2.0 | 0 — 5.5 ND — 0.8 | | |
| | VIN1 (L) | FPWM, CW_CCW, SEL_LAP, BRAKE | GND | _ | 0.8 | V |
| Input voltage | V _{IN2} (H) | | 4 | _ | | |
| | V _{IN2} (M) | FST, SLOP, LA | 2 | _ | 3 | |
| | VIN2 (L) | | GND | _ | 1 | |
| Input voltage hysteresis | Vhys | FPWM, CW_CCW, SEL_LAP, BRAKE | _ | 0.45 | _ | V |
| Charge current of the TIP and TRE pins | Ich | OSC_R = 20 kΩ | 2.4 | 3 | 3.6 | μА |
| Setting time of the TIP and TRE pins | Tipre | TIP = 1 μF, TRE = 1 μF, OSC_R = 20 kΩ | _ | 1 | _ | S |
| Detection voltage of the TIP and TRE pins | V _{DET} | - | 2.8 | 3 | 3.2 | ٧ |
| COM input current | I _{com} | COM = 6 V, VSP = VST = 2.5 V | -1 | 0 | 1 | μА |
| Low-level FG_OUT output voltage | V _{FG_OUT} | IFG_OUT = 5 mA | GND | _ | 0.5 | V |
| FG_OUT leakage current | I _{LFG_OUT} | V _{FG_OUT} = 5.5 V | _ | 0 | 10 | μА |

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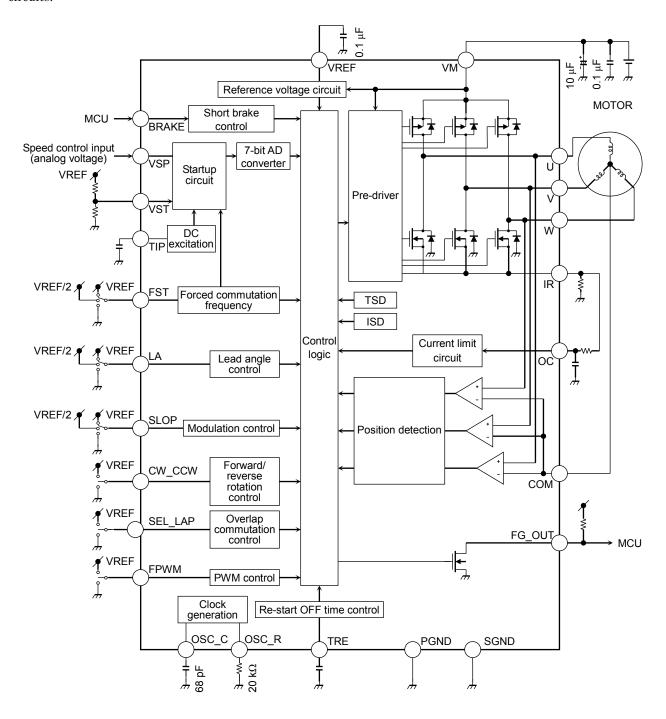
| Characteristics | Symbol | Test Conditions | Min | Тур. | Max | Unit | |
|----------------------------------------------------|----------------------|------------------------------------------|-------|------|----------------------------------------------|-------|--|
| | Ron1 (H) | IOUT = 0.6 A | _ | 0.4 | 0.65 | | |
| | Ron1 (L) | I _{OUT} = -0.6 A | _ | 0.4 | 0.65 | | |
| | R _{ON2} (H) | I _{OUT} = 1.0 A | _ | 0.4 | 0.65 | | |
| Output ON-resistance of the U, V and W pins | R _{ON2} (L) | I _{OUT} = −1.0 A | _ | 0.4 | 0.65 | | |
| | Rons (H) | I _{OUT} = 0.6 A, VM = 4.5 V | _ | 0.45 | 0.75 | Ω | |
| | Ron3 (L) | I _{OUT} = -0.6 A, VM = 4.5 V | _ | 0.45 | 0.75 | | |
| | Ron4 (H) | I _{OUT} = 1.0 A, VM = 4.5 V | _ | 0.45 | 0.75 | | |
| | R _{ON4} (L) | I _{OUT} = -1.0 A, VM = 4.5 V | _ | 0.45 | 0.75 | | |
| Output leakage current of the | IL (H) | Vout = 0 V | _ | 0 | 0.65 0.65 0.65 0.65 0.75 0.75 | | |
| U, V and W pins | IL (L) | V _{OUT} = 25 V | _ | 0 | 10 | μА | |
| Output diodes' forward voltage | V _F (H) | I _{OUT} = 1.0 A | _ | 1.0 | 1.4 | ., | |
| of the U, V and W pins | V _F (L) | I _{OUT} = -1.0 A | _ | 1.0 | 1.4 | V | |
| VSP reset input voltage | Vvspr | _ | 0.9 | 1.0 | 1.1 | V | |
| DIMM in part welfers | V _{AD} (L) | VSP = VST, FPWM = L | 0.9 | 1.0 | 1.1 | V | |
| PWM input voltage | Vad (H) | 000 0 - 00 - 000 D - 2010 | 3.6 | 4.0 | 4.2 | | |
| OC pin voltage for current detection | Voc1 | _ | 0.225 | 0.25 | 0.275 | V | |
| OC pin voltage threshold for overcurrent detection | V _{OC2} | _ | 0.675 | 0.75 | 0.825 | V | |
| | F _{C1} (H) | FPWM = H OSC_C = 68 pF, OSC_R = 20 kΩ | 36 | 40 | 44 | 1.1.1 | |
| PWM frequency | F _{C1} (L) | FPWM = L OSC_C = 68 pF, OSC_R = 20 kΩ | 18 | 20 | 22 | - kHz | |
| OSC frequency | OSC | OSC_C = 68 pF, OSC_R = 20 kΩ | 4.55 | 5.1 | 5.65 | MHz | |
| ISD trip threshold | I _{ISD} | _ | _ | 2 | _ | Α | |
| T | TSD | _ | _ | 165 | _ | 0.0 | |
| Thermal shutdown | TSDhys | Thermal shutdown hysteresis | _ | 15 | _ | °C | |
| UVLO trip threshold voltage of the VM pin | VMLVD | _ | _ | 3.5 | _ | V | |
| UVLO recovery voltage of the VM pin | VMLVDR | _ | _ | 4.0 | _ | ٧ | |
| UVLO trip threshold voltage of the VREF pin | VRELVD | _ | _ | 3.5 | _ | V | |
| UVLO recovery voltage of the VREF pin | V _{RERLVD} | _ | _ | 4.0 | _ | V | |
| VDEE autout on !! | VREF1 | IVREF = -5 mA | 4.5 | 5 | 5.5 | V | |
| VREF output voltage | VREF2 | IVREF = -5 mA, VM = 4.5 V | 4.0 | 4.3 | 4.5 | V | |

Application Circuit Example

Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purposes.

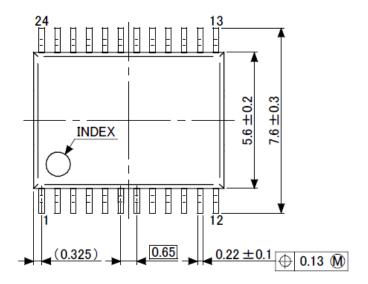
The application circuits shown in this document are provided for reference purposes only. Thorough evaluation is required, especially at the mass production design stage.

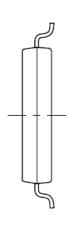
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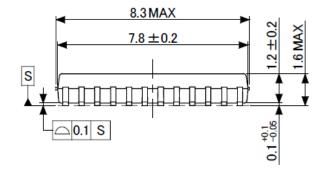
Package Dimensions

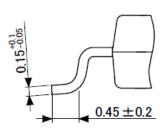
SSOP24-P-300-0.65A "Unit: mm"





Detailed diagram of tip of terminal





Weight: 0.136 g (typ.)

Notes on Contents

1. Block Diagrams

Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purposes.

2. Equivalent Circuits

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

3. Timing Charts

Timing charts may be simplified for explanatory purposes.

4. Application Circuits

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5. Test Circuits

Components in the test circuits are used only to obtain and confirm the device characteristics. These components and circuits are not guaranteed to prevent malfunction or failure from occurring in the application equipment.

IC Usage Considerations

Notes on handling of ICs

- (1) The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings.
 Exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.
- (2) Use an appropriate power supply fuse to ensure that a large current does not continuously flow in case of over current and/or IC failure. The IC will fully break down when used under conditions that exceed its absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs from the wiring or load, causing a large current to continuously flow and the breakdown can lead smoke or ignition. To minimize the effects of the flow of a large current in case of breakdown, appropriate settings, such as fuse capacity, fusing time and insertion circuit location, are required.
- (3) If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design to prevent device malfunction or breakdown caused by the current resulting from the inrush current at power ON or the negative current resulting from the back electromotive force at power OFF. IC breakdown may cause injury, smoke or ignition.

 Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.
- (4) Do not insert devices in the wrong orientation or incorrectly.
 - Make sure that the positive and negative terminals of power supplies are connected properly. Otherwise, the current or power consumption may exceed the absolute maximum rating, and exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.
 - In addition, do not use any device that is applied the current with inserting in the wrong orientation or incorrectly even just one time.



Points to remember on handling of ICs

(1) Over current Protection Circuit

Over current protection circuits (referred to as current limiter circuits) do not necessarily protect ICs under all circumstances. If the Over current protection circuits operate against the over current, clear the over current status immediately.

Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the over current protection circuit to not operate properly or IC breakdown before operation. In addition, depending on the method of use and usage conditions, if over current continues to flow for a long time after operation, the IC may generate heat resulting in breakdown.

(2) Thermal Shutdown Circuit

Thermal shutdown circuits do not necessarily protect ICs under all circumstances. If the thermal shutdown circuits operate against the over temperature, clear the heat generation status immediately. Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the thermal shutdown circuit to not operate properly or IC breakdown before operation.

(3) Heat Radiation Design

In using an IC with large current flow such as power amp, regulator or driver, please design the device so that heat is appropriately radiated, not to exceed the specified junction temperature (Tj) at any time and condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, please design the device taking into considerate the effect of IC heat radiation with peripheral components.

(4) Back-EMF

When a motor rotates in the reverse direction, stops or slows down abruptly, a current flow back to the motor's power supply due to the effect of back-EMF. If the current sink capability of the power supply is small, the device's motor power supply and output pins might be exposed to conditions beyond absolute maximum ratings. To avoid this problem, take the effect of back-EMF into consideration in system design.

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